

PRODUCT/PROCESS CHANGE NOTIFICATION PCN13410 – Additional information

ST MUAR (Malaysia) die attach material (Glue) additional source for STM32 LQFP 14x14 SHD 100L package - on listed products

MDG - Microcontrollers Division (MCD)

What are the changes?

Changes described in table below:

	Existing back-end lines	Added
		back-end line
Assembly site	ST Mua	ar Malaysia
Die Attach Material	GLUE LOCTITE ABLESTIK	GLUE HITACHI
	ABP8302	EN4900GC



How to order samples?

- For all samples request linked to this PCN, please: place a <u>Non-standard</u> sample order (choose Sample Non Std Type from pull down menu) •
- insert the PCN number "PCN13410" into the NPO Electronic Sheet/Regional Sheet ٠
- request sample(s) through Notice tool, indicating a single Commercial Product for each request •

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MMS- MCD RER1514 Reliability Report

Qualification Type : ASSEMBLY LINE QUALIFICATION, NEW BILL OF MATERIALS

LQFP 7x7 48L - ST Muar Qualification Dice 410/427/765

(PCN MMS-MIC/15/9484 dated 30 Oct 2015)

Product / Process & Package Information	Die 410	Die 427	Die 765				
Commercial Product:	STM32F103CBT6	STM32L152CCT6	STM8S207C8T6				
Product Line:	STM32F die 410	STM32L die 427	STM8S die 765				
Product Description:	Micro 3	2Bits	Micro 8Bits				
Finish Good Code:	ES32F103CBT6\$J8	ES32L152CCT6\$B6	ES8S207C8T6\$9C				
Mask Set Revision:	X410XXXX	X427XXXV	X765XXXV				
Silicon Process Technology:	0.18 M8 EMBEDDED FLASH	8X - CMOSF9S	2V - CMOSF9				
Wafer Fabrication	TSMC	ST	ST				
Location:	Fab 3	Rousset 8	Rousset 8				
	Taiwan	France	France				
	ST MICROELE	CTRONICS	ARDENTEC				
Electrical Wafer Sort	Ang Mo	o Kio	Hsinchu				
Test Plant Location:	EWS	S	EWS				
	SINGAF	PORE	Taiwan				
Package:		LQFP 48 7x7x1.4					
Assembly Plant	ST Muar (Malaysia)						
location:		ST Muar (Malaysia)					
Final Test plant location:		ST Muar (Malaysia)					

Approval List			
Function	Location	Name	Date
Division Q&R Responsible	ST Rousset	Gisèle SEUBE	May31st, 2016
Division Quality Manager	ST Rousset	Pascal NARCHE	May31st, 2016



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1 RELIABILITY RESULTS OVERVIEW

1.1 Objectives

This report summarizes the reliability results for LQFP 48 7x7 package manufactured at ST Muar (Malaysia). Test vehicles are described here below:

Product	Package
STM32F103CBT6	LQFP 48 7x7x1.4
STM32L152CCT6	LQFP 48 7x7x1.4
STM8S207C8T6	LQFP 48 7x7x1.4

1.2 Context

In order to increase assembly capacity, ST Microcontrollers Division has decided to add a High Density line in ST Muar (Malaysia) assembly site, for LQFP 48 7x7 products.

New Bill of Materials changes are described here below for LQFP 7x7 48L products:

		Existing Bill Of Materials					
Assembly site	STATS ChipPAC	Amkor ATP (Philippines)	ST Muar (Malaysia)	ST Muar (Malaysia)			
	Shanghai (China)						
Wire	Gold 0.8mil	Gold 0.8mil	Gold 0.8mil	Silver 0.8mil			
Leadframe	Copper Frame	Copper Frame Spot Ag	Pre Plated Frame	Pre Plated Frame			
	Spot Ag						
Leadfinishing (*1)	Pure Tin (e3)	Pure Tin (e3)	Rough Ni Pd AgAu (e4)	Rough Ni Pd AgAu (e4)			
Resin	Sumitomo G700E	Sumitomo G631HQ	Sumitomo G700LS	Sumitomo G700LS			
Glue	Ablestik 3230	Evertech AP4200	Hitachi EN4900	Hitachi EN4900			

According to the positive reliability results, the qualification is granted for High Density assembly line in ST Muar (Malaysia).



2 **RELIABILITY TEST VEHICLES Characteristics**

2.1 Reliability Test vehicles description

Package line	Assembly Line	Package	Device (Partial RawLine Code)	Diffusion Process	Number of Lots
HD LQFP	LQFP7*7	48L	STM8S (5B*765) STM32F (5B*410) STM32L (5B*427)	F9GO1 TSMC 0.18µm F9GO2S	1 1 1

2.2 Reliability Information

Lot ID	Lot 1	Lot 2	Lot 3		
Die Name /cut:	410	427	765		
Diffusion Lot Number:	93537129	VG536347	VG540309		
Trace Code:	995510CH	995510CQ	995510CR		
Assy lot number	995510CH01	995510CQ01	995510CR01		
Raw Line Code Package:	J55B*410ESXX	U05B*427ESXV	J15B*765ESXV		
Reliability Lab location :	ST Muar (Malaysia)				



2.3 Front-End information

Front-End	Lot 1 (410)	Lot 2 (427)	Lot 3 (765)				
Wafer Diameter:		8 inches	I				
Wafer Thickness:		375 +/-25 μm					
Die Size:	3.3908 X 3.328 mm	3.263 X 4.199 mm	3.010 X 2.458 mm				
Scribe Line size x/y:		80 x 80 μm					
Pad Die Size /Pad type:	59 x 123 µm	53 x 108 μm	65 x 108 μm				
Metal Layers Number /Materials /Thickness: Passivation	Metal 1 Tin/AlCu/Tin 0.450 μm Metal 2 Tin/AlCu/Tin 0.450 μm Metal 3 Tin/AlCu/Tin 0.450 μm Metal 4 Tin/AlCu/Tin 0.450 μm Metal 5 Tin/AlCu/Tin 0.875 μm	Metal 1 TaN/Ta/Cu 0.280 μm Metal 2 Ti/AlCu/TxTN 0.310 μm Metal 3 Ti/AlCu/TxTN 0.310 μm Metal 4 Ti/AlCu/TxTN 0.310 μm Metal 5 Ti/AlCu/TxTN 1.200 μm	Metal 1 TaN/Ta/Cu 0.280 μm Metal 2 TaN/Ta/Cu 0.350 μm Metal 3 TaN/Ta/Cu 0.350 μm Metal 4 Ti/AICu/TxTN 0.900 μm				
Layers Thickness:	HDPox 10kA+SRO 1.5kA+PESIN 6kA USG + NitUV (HFP USG+UV Nitride)						
Back Metal Finishing	R	RAW SILICON - BACK GRINDING					



2.4 Back-End information

Back-End	Lot 1 (410)	Lot 2 (427)	Lot 3 (765)		
Assembly Plant Location/ Address:	8	ST MICROELECTRONICS TANJONG AGAS IND ESTATE PO BOX 28 84007 MUAR / JOHOR MALAYSIA			
Die Thickness after Back grinding:	NA	NA	NA		
Die sawing method:		Step cut			
Die attach material: Type: Supplier:		Glue EN4900 ST16 Hitachi			
Lead frame material: L/F Finishing	Copper LF-HD Rough μPPF (ε	Copper LF-HD LQFP 48L 7x7 Rough µPPF (e4) Ni Pd AuAg			
Type: Die paddle size: Supplier:	5 > HE	5 x 5 HDS			
Wire bonding: Type /Diameter: Supplier:		AG 96,5% WIRE 0.8MIL MKE			
Pitch:	80µm	70µm	80,36µm		
POA:		0110596			
Molding Compound Supplier:	EME-G700LS SUMITOMO				
Package Moisture Sensitivity Level (JEDEC J-STD020D):		2			



3 RELIABILITY RESULTS SUMMARY

3.1 Die oriented test

	Die Related Tests						Results LQFP 7x7		
Description	Test/Method	Conditions	Sample Size	Criteria	Readout / Duration	410	427	765	
Electrostatic o	Electrostatic discharge – Charge Device Model								
ESD CDM	ANSI/ESD STM5.3.1	500V 1KV	3 units	500V for dice 410/427 1KV for 765	NA	0/3	0/3	0/3	

3.2 Package Oriented Test

	Package Related Tests				Results LQFP 7x7				
Description	Test/Method	Conditions	Sample Size	Criteria	Readout / Duration	410	427	765	
Preconditioning:	Preconditioning: moisture sensitivity level 1								
PC	J-STD-020 JESD22- A113	MSL1 For MSL2 Qual	308 units	Electrical test: A0/R1 (Accepted 0 reject/ Rejected 1 reject)	NA	0/308			
High Temperature Storage Life									
HTSL	JESD 22-A103	150°C	77 units	Elect test A0/R1	1000h	0/77	0/77	0/77	
Thermal Cycling	after Preconditioning								
тс	JESD 22-A104	-65c/+150°c	77 units	Elect test A0/R1	100cy 500cy 1000cy	0/77 0/77 0/77	0/77 0/77 0/77	0/77 0/77 0/77	
Wire Bond Shear after Thermal Cycling									
Wire Bond Shear	AEC Q100-001	Min bond shear 15g after TC	30 x 3	A0/R1	After TC 500cy TC 1000cy	0/30	0/30	0/30	
Wire Bond Pull a	after Thermal Cycling	•							
Wire Bond Pull	Mil Std 883 Method 2011	Minimum pull strength after TC=3 grams after TC	30 x 3	A0/R1	After TC 500cy TC 1000cy	0/30	0/30	0/30	



Autoclave after Preconditioning								
AC	JESD 22A102	121°C ,100% 2Atm RH	77 units	Elect test A0/R1	96h	0/77	0/77	0/77
Temperature Humidity Bias after Preconditioning								
ТНВ	JESD 22A110	85°C/85%RH Bias	77 units	Elect test A0/R1	1000h	0/77	0/77	0/77
Construction Analysis								• •
CA	Construction Analysis including : -Wire bond shear -Wire bond pull -Solderability -Physical Dimension	JESD 22B102 JESDB100/B108	50		No major concern	No major concern		cern



4 APPLICABLE AND REFERENCE DOCUMENTS

ADCS/DMS 0061692 :	Reliability Tests And Criteria For Qualifications			
SOP 2.6.2: Process qualification and transfer management				
SOP 2.6.7: Product Maturity Level				
SOP 2.6.9:	Package and process maturity management in Back End			
SOP 2.6.11: Program management from product qualification				
SOP 2.6.19: Process maturity level				
ANSI-ESD STM5.3.1: Electrostatic discharge (ESD) sensitivity testing charge device model (CDM)				
JESD 22-A103 High Temperature Storage Life				
J-STD-020D: Moisture/reflow sensitivity classification for non-hermetic solid state surface mour				
JESD22-A113:	Preconditioning of non-hermetic surface mount devices prior to reliability testing			
JESD22-A102:	Autoclave test (pressure pot)			
JESD22-A104:	Temperature cycling			
JESD22-A110:	Temperature Humidity Bake			
JESD 22B102: Solderability test				
JESD22B100/B108:	Physical dimension			

5 GLOSSARY AND TESTS DESCIPTION

PC	Preconditioning (solder simulation)
ТНВ	Temperature Humidity Bias
тс	Temperature cycling
AC	Autoclave test (pressure pot)
HTSL	High temperature storage life
ADCS/DMS	ST Advanced Documentation Controlled system/ Documentation Management system
ESD CDM	Electrostatic discharge (charge device model)
CA	Construction Analysis

6 **REVISION HISTORY**

Version	Date	Author	Comment
1.0	May 31st, 2016	Olivier GIRAUD	Initial release for qualification



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